



SANYO Semiconductors

DATA SHEET

An ON Semiconductor Company

2SA1418/2SC3648 — PNP / NPN Epitaxial Planar Silicon Transistor

High-Voltage Switching, Preriver Applications

Applications

- Color TV audio output, inverter

Features

- Adoption of FBET, MBIT processes
- Fast switching speed
- Ultrasmall size making it easy to provide high-density, small-sized hybrid IC's
- High breakdown voltage and large current capacity

Specifications () : 2SA1418

Absolute Maximum Ratings at Ta=25°C

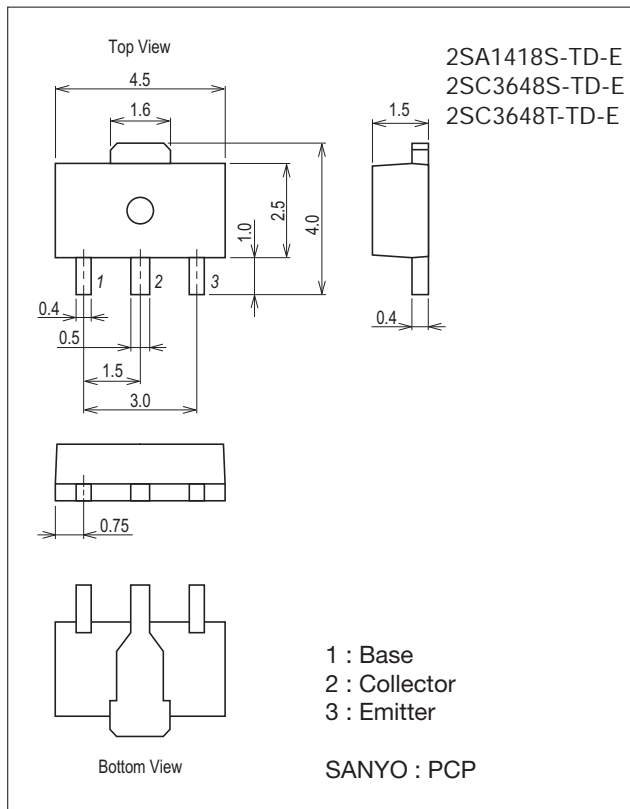
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(-)180	V
Collector-to-Emitter Voltage	V _{CEO}		(-)160	V
Emitter-to-Base Voltage	V _{EBO}		(-)6	V
Collector Current	I _C		(-)0.7	A
Collector Current (Pulse)	I _{CP}		(-)1.5	A

Continued on next page.

Package Dimensions

unit : mm (typ)

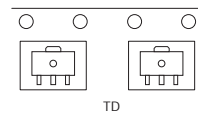
7007B-004



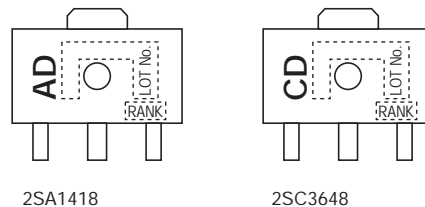
Product & Package Information

- Package : PCP
- JEITA, JEDEC : SC-62, SOT-89, TO-243
- Minimum Packing Quantity : 1,000 pcs./reel

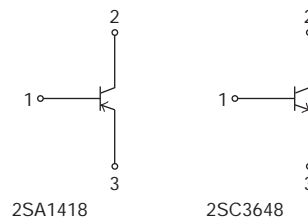
Packing Type: TD



Marking



Electrical Connection



2SA1418 / 2SC3648

Continued from preceding page.

Parameter	Symbol	Conditions	Ratings	Unit
Collector Dissipation	P _C		500	mW
		When mounted on ceramic substrate (250mm ² ×0.8mm)	1.3	W
Junction Temperature	T _j		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

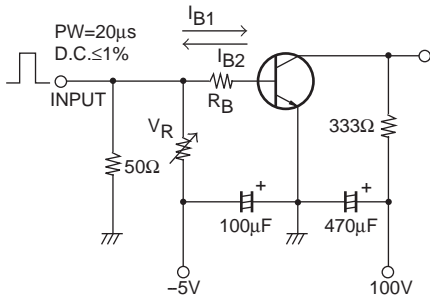
Electrical Characteristics at T_a=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CBO}	V _{CB} =(-)120V, I _E =0A			(-)0.1	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =(-)4V, I _C =0A			(-)0.1	μA
DC Current Gain	h _{FE1}	V _{CE} =(-)5V, I _C =(-)100mA	100*		400*	
	h _{FE2}	V _{CE} =(-)5V, I _C =(-)10mA	90			
Gain-Bandwidth Product	f _T	V _{CE} =(-)10V, I _C =(-)50mA		120		MHz
Output Capacitance	C _{ob}	V _{CB} =(-)10V, f=1MHz		(1)8		pF
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)250mA, I _B =(-)25mA	(-0.2)0.12		(-0.5)0.4	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)250mA, I _B =(-)25mA	(-)0.85		(-)1.2	V
Collector-to-Base Breakdown Voltage	V _{(BR)CBO}	I _C =(-)10μA, I _E =0A	(-)180			V
Collector-to-Emitter Breakdown Voltage	V _{(BR)CEO}	I _C =(-)1mA, R _{BE} =∞	(-)160			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _E =(-)10μA, I _C =0A	(-)6			V
Turn-ON Time	t _{on}	See specified Test Circuit.		(60)50		ns
Storage Time	t _{stg}			(900)1000		ns
Fall Time	t _f			(60)60		ns

* : The 2SA1418 / 2SC3648 are classified by 100mA h_{FE} as follows :

Rank	R	S	T
h _{FE}	100 to 200	140 to 280	200 to 400

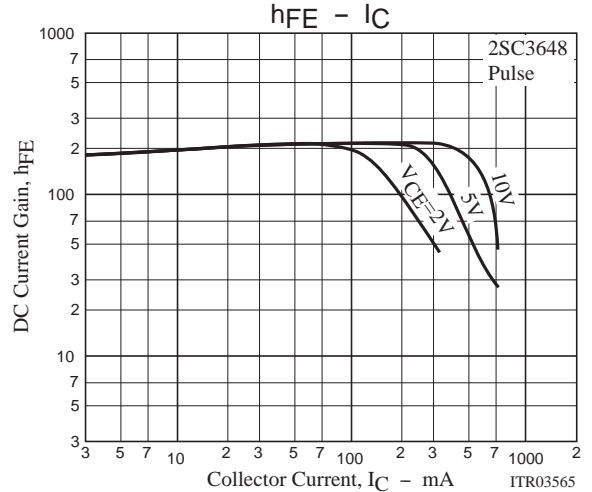
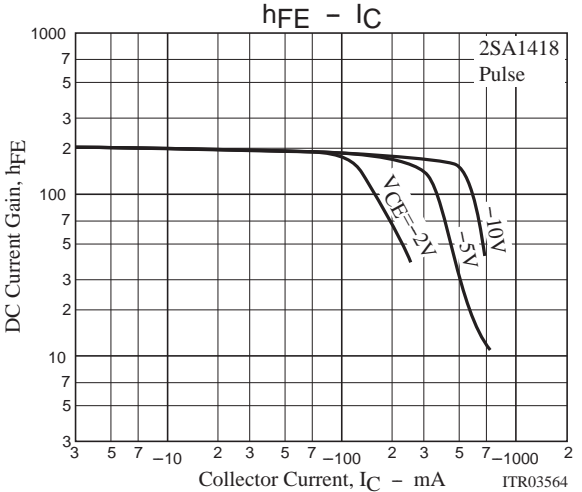
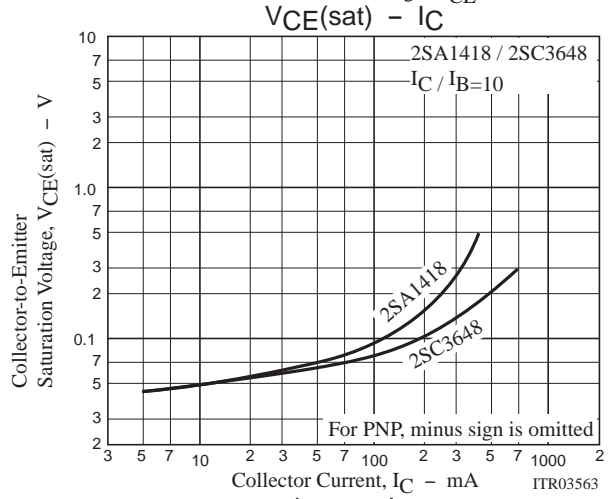
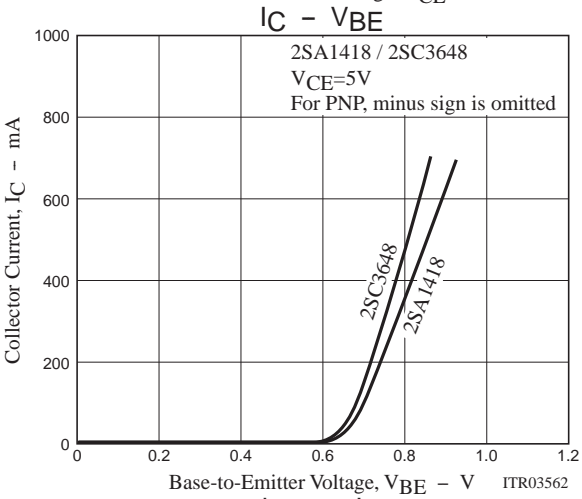
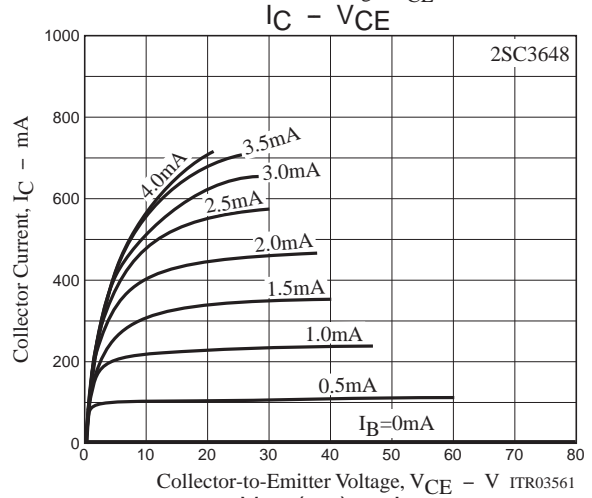
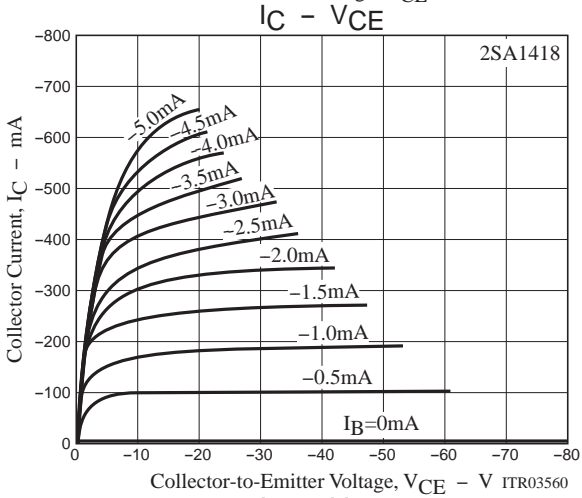
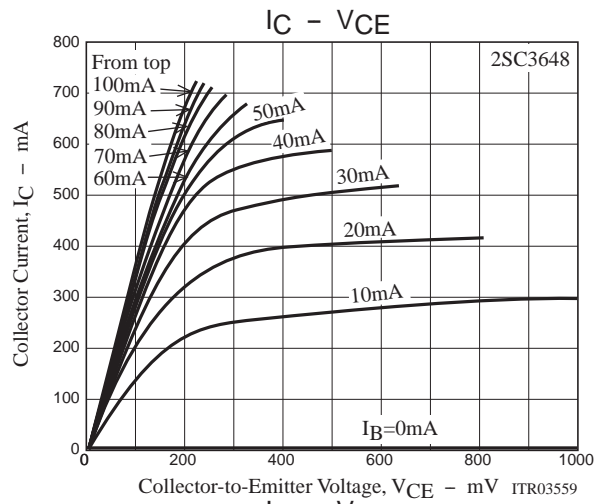
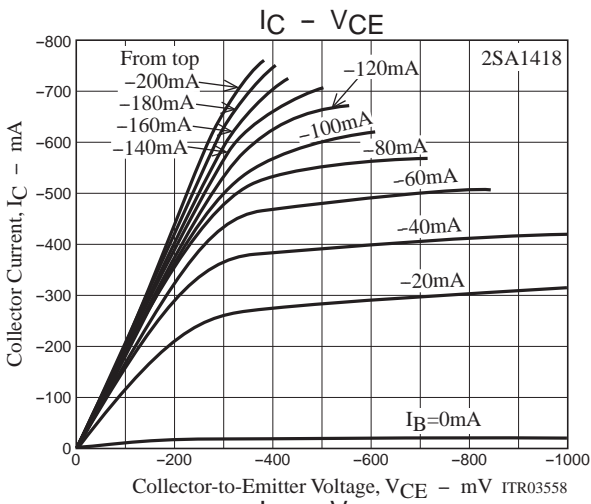
Switching Time Test Circuit

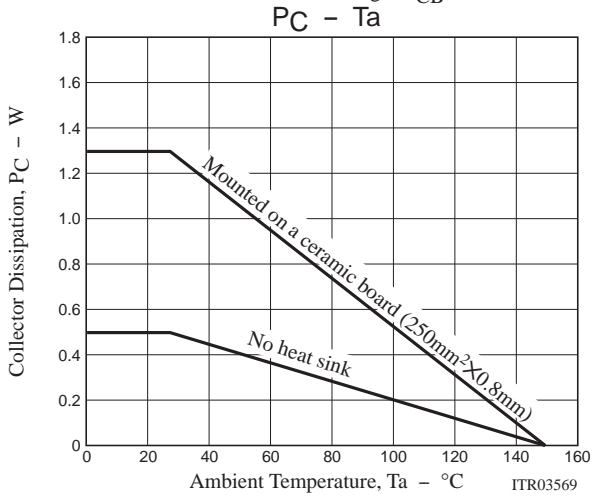
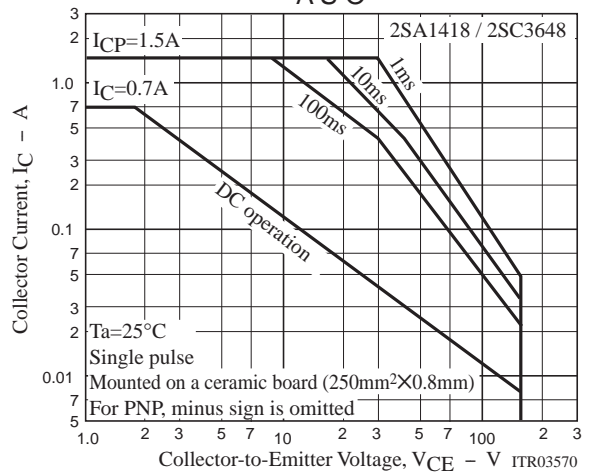
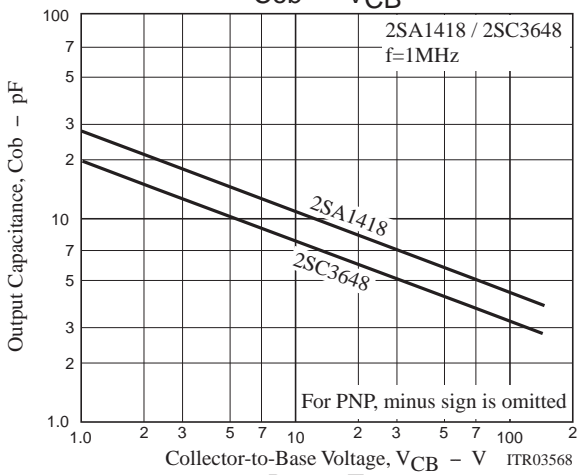
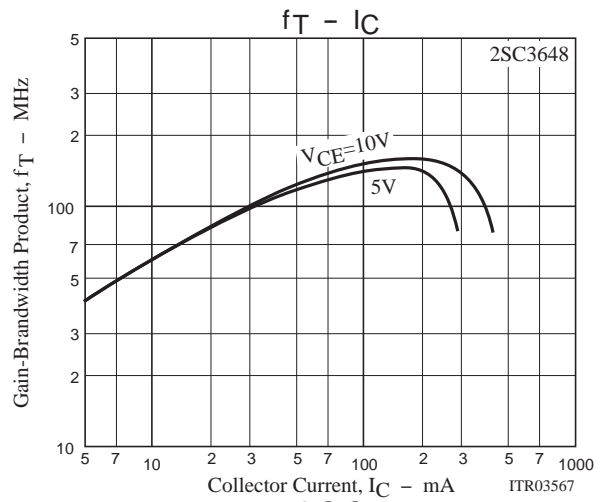
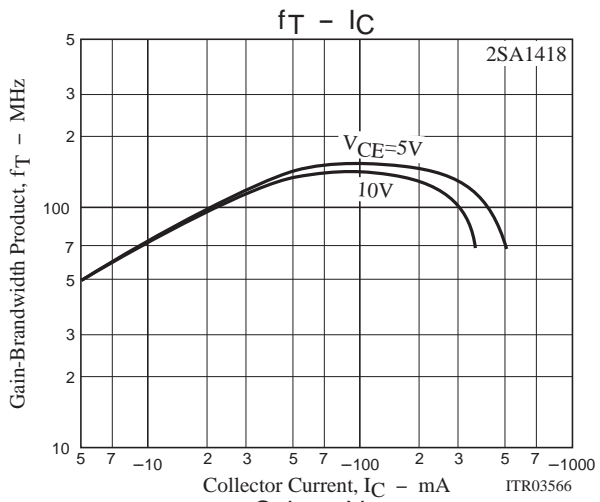


I_C=20I_{B1}=-20I_{B2}=300mA
(For PNP, the polarity is reversed)

Ordering Information

Device	Package	Shipping	memo
2SA1418S-TD-E	PCP	1,000pcs./reel	Pb Free
2SC3648S-TD-E	PCP	1,000pcs./reel	
2SC3648T-TD-E	PCP	1,000pcs./reel	





Bag Packing Specification

2SA1418S-TD-E, 2SC3648S-TD-E, 2SC3648T-TD-E

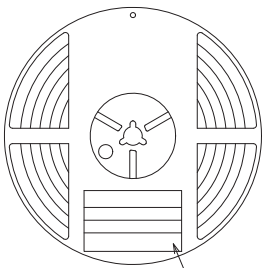
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
PCP	PCP	1,000	4,000	24,000	4 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Reel label, Inner box label
(unit :mm)

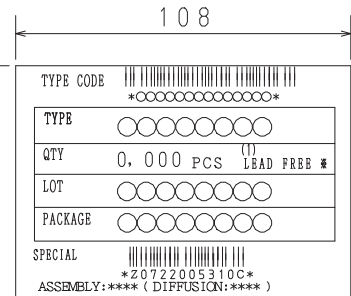
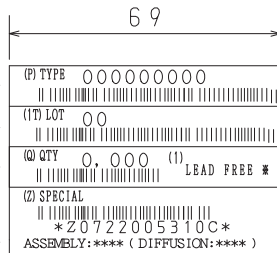
Outer box label
It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

Packing method



Reel label

Type No.
LOT No.
Quantity
Origin



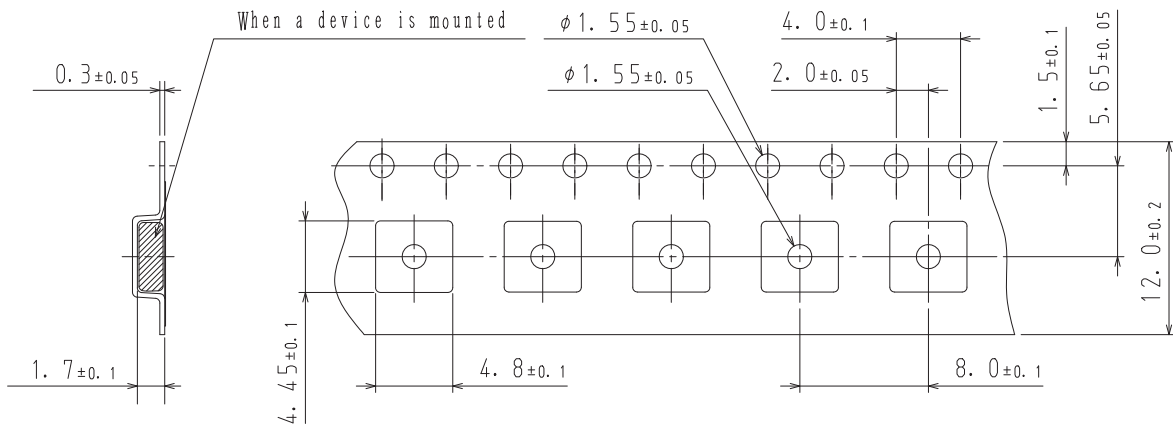
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

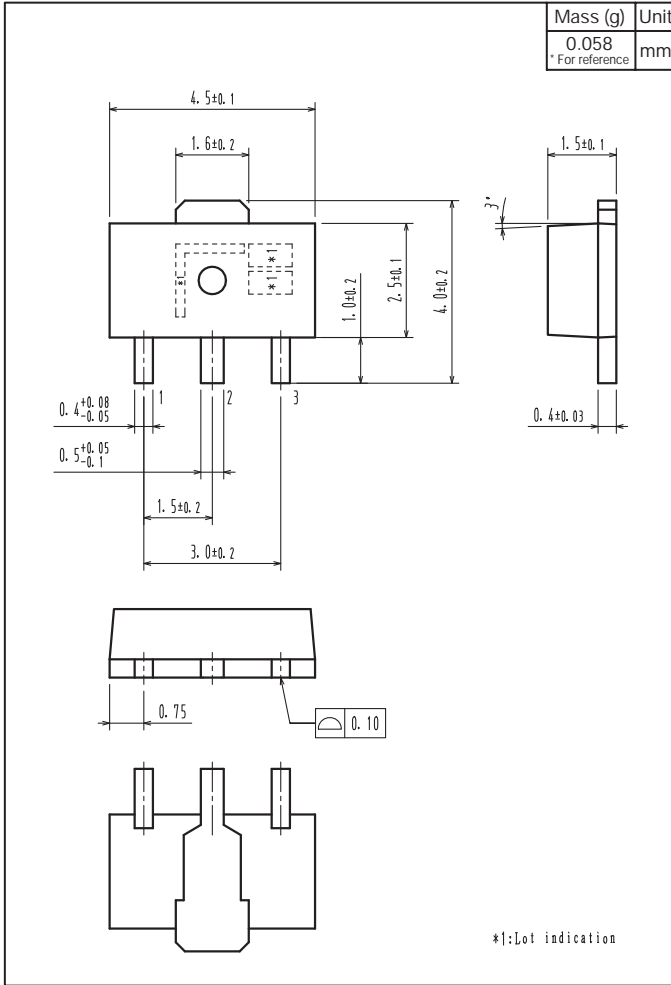


Those with pin 1 index on the feed hole side.....TD

2SA1418 / 2SC3648

Outline Drawing

2SA1418S-TD-E, 2SC3648S-TD-E, 2SC3648T-TD-E



Land Pattern Example



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